



### v01.0414 GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

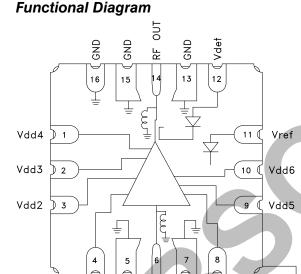
#### **Typical Applications**

The HMC5846LS6 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM
- Military & Space

#### Features

Saturated Output Power: 35.5 dBm @ 30% PAE High Output IP3: 42.5 dBm High Gain: 31 dB DC Supply: +7V @ 1200 mA No External Matching Required



Z

GND

/dd1

#### **General Description**

The HMC5846LS6 is a 4 stage GaAs pHEMT MMIC 2 Watt Power Amplifier with an integrated temperature compensated power detector which operates between 12 and 16 GHz. The HMC5846LS6 provides 31 dB of gain, 35.5 dBm of saturated output power, and 30% PAE from a +7V supply. The HMC5846LS6 exhibits excellent linearity and is optimized for high capacity digital microwave radio. It is also ideal for 13.75 to 14.5 GHz Ku Band VSAT transmitters as well as SATCOM applications.

### **Electrical Specifications,** $T_A = +25 \,^{\circ}\text{C}$ Vdd = Vdd1, Vdd2, Vdd3, Vdd4, Vdd5 = +7V, Idd = 1200 mA<sup>[1]</sup>

.66/

PACKAGE

BASE

Parameter	Min.	Тур.	Max.	Units
Frequency Range		12 - 16		GHz
Gain	26	31		dB
Gain Variation Over Temperature		0.06		dB/ °C
Input Return Loss		10		dB
Output Return Loss		17		dB
Output Power for 1 dB Compression (P1dB)	32.5	34.5		dBm
Saturated Output Power (Psat)		35.5		dBm
Output Third Order Intercept (IP3) <sup>[2]</sup>		42.5		dBm
Total Supply Current (Idd)		1200		mA

[1] Adjust Vgg between -2 to 0V to achieve Idd = 1200 mA typical.

[2] Measurement taken at +7V @ 1200 mA, Pout / Tone = +22 dBm

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**Broadband Gain &** 

## HMC5846LS6

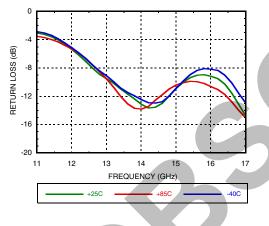


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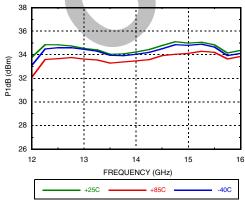
**Return Loss vs. Frequency** 40 30 20 (qB) RESPONSE 10 C -10 -20 -30 10 11 12 14 15 16 17 18 13 FREQUENCY (GHz) S21 S11 S22

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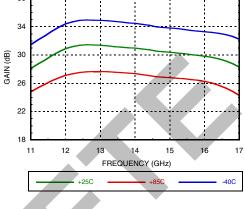
Input Return Loss vs. Temperature



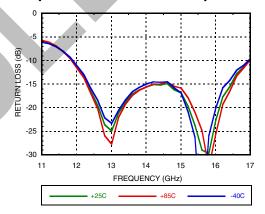




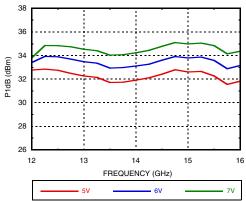
Gain vs. Temperature



**Output Return Loss vs. Temperature** 







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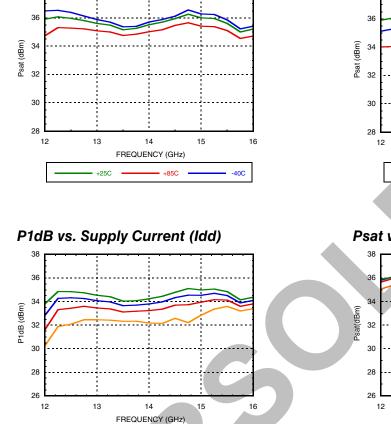
Psat vs. Temperature



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## GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

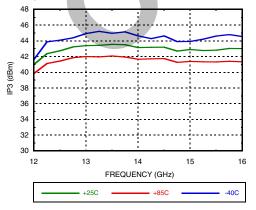




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Output IP3 vs. Temperature, Pout/Tone = +22 dBm

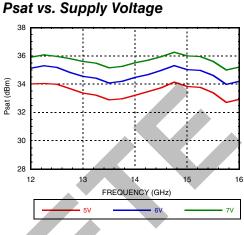
1000mA



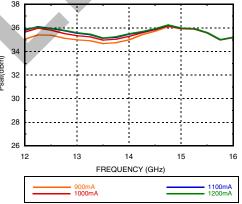
#### [1] Footnote if needed

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1200mA

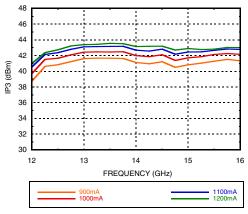


Psat vs. Supply Current (Idd)



Output IP3 vs.

Supply Current, Pout/Tone = +22 dBm

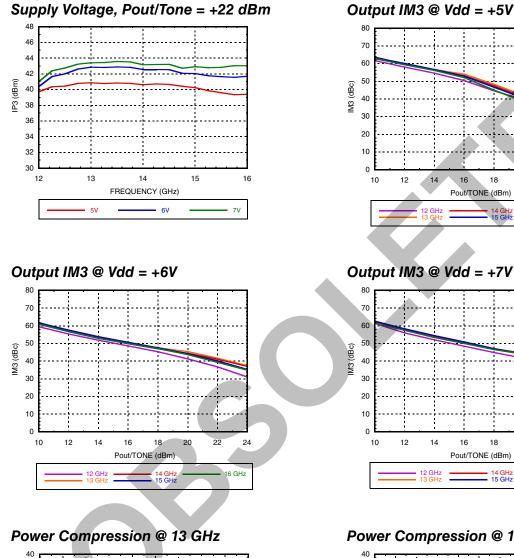




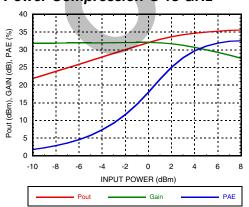


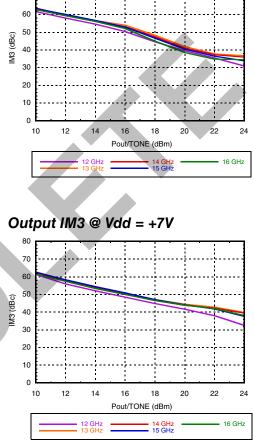
Output IP3 vs.

### GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

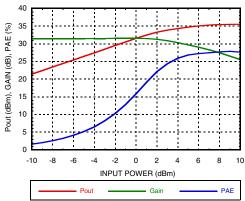


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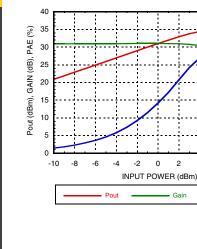
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## GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

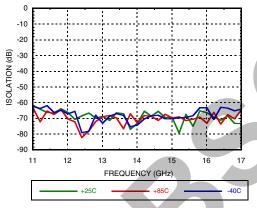


**Power Compression @ 15 GHz** 

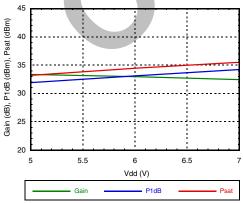
**Reverse Isolation vs. Temperature** 

4 6 8 10

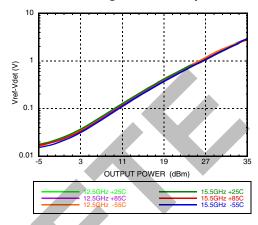
PAE



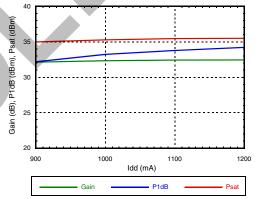
Gain & Power vs. Supply Voltage @ 14 GHz



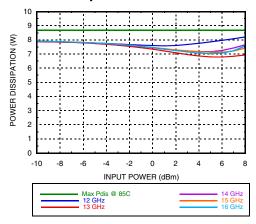
Detector Voltage Over Temperature



Gain & Power vs. Supply Current @ 14 GHz



### **Power Dissipation**



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### GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

### Absolute Maximum Ratings

+8V +24 dBm
+24 dBm
150 °C
8.6 W
7.55 °C/W
-65 to +150 °C
-55 to +85 °C
Class 1A Pass 250V

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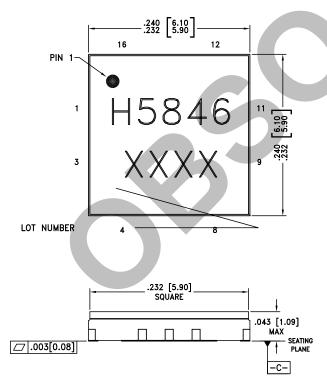
### **Reliability Information**

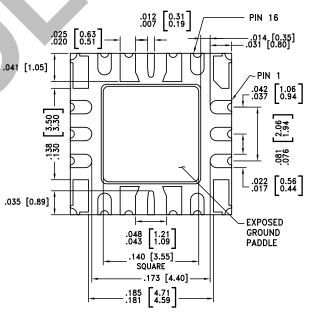
Junction Temperature to Maintain 1 Million Hour MTTF	150 °C
Nominal Junction Temperature (T= 85 °C and Pin = 10 dBm)	90 °C
Operating Temperature	-55 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS** 

### **Outline Drawing**





### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating <sup>[2]</sup>	Package Marking <sup>[1]</sup>
HMC5846LS6	ALUMINA WHITE	Gold over Nickel	N/A	<u>H5846</u> XXXX

[1] 4-Digit lot number XXXX [2] Max peak reflow temperature of 260 °C

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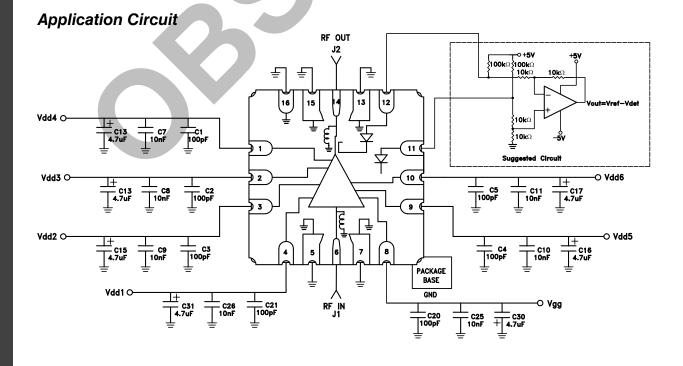


## GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz

### **Pin Descriptions**

Pad Number	Function	Description	Interface Schematic
6	RFIN	This Pin is DC coupled and matched to 50 Ohms over the operating frequency.	RFIN O
1-4 9, 10	Vdd4, Vdd3, Vdd2, Vdd1, Vdd5, Vdd6	Drain bias voltage for the amplifier. External bypass capaci- tors of 100 pF are required for each pin followed by 0.01 µF capacitors and a 4.7 µF capacitors.	OVdd1−6
8	Vgg1	Gate controlled amplifier. External bypass capacitors of 100 pF are required followed by 0.01 µF capacitors and a 4.7 µF capacitors.	Vgg10
5, 7, 13, 15, 16	GND	These Pins and Package bottom must be connected to RF/DC ground.	
11	Vref	DC voltage of diode biased through external resistor, used for temperature compensation of Vdet.	OVref
12	Vdet	DC voltage representing RF output rectified by diode which is biased through an external resistor.	OVdet
14	RFOUT	This Pin is DC coupled and matched to 50 Ohms.	

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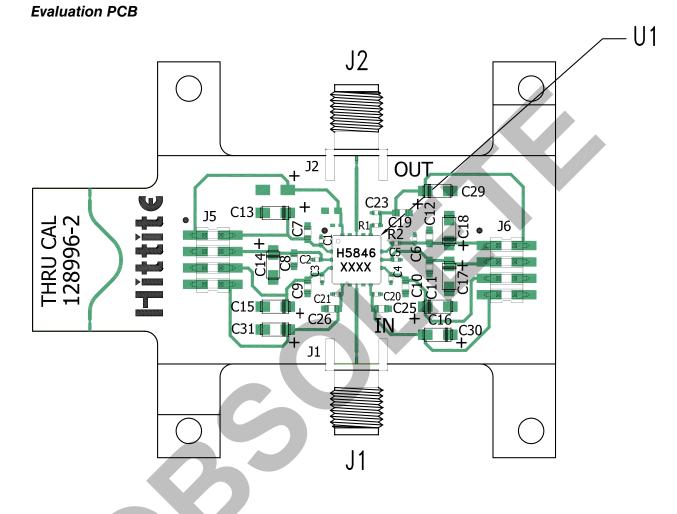


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ROHS

## GaAs pHEMT MMIC 2 WATT POWER AMPLIFIER WITH POWER DETECTOR, 12 - 16 GHz



### List of Materials for Evaluation PCB EVAL01-HMC5846L56 [1]

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Item	Description	
J1, J2	PCB Mount K Connectors, SRI	
J5, J6	DC Pins	
C1 - C6, C20, C21, C23	100 pF Capacitors, 0402 Pkg.	
C7 - C12, C19, C25, C26	0.01 µF Capacitors, 0603 Pkg.	
C13 - C18, C29 - C31	4.7 µF Capacitors, Case A Pkg.	
R1 - R2	40.2 kOhm Resistor, 0402 Pkg.	
U1 HMC5846LS6 Amplifier		
PCB [2]	128996 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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